

Supporting Information for the manuscript:

**A Single Molecule Magnet to Single Molecule Magnet
Transformation via a Solvothermal Process: $\text{Fe}_4\text{Dy}_2 \rightarrow$
 Fe_6Dy_3**

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Table S1 Magnetic data of compounds **1-4** summarised from the dc measurements.

Compound	Ground state of Ln ^{III}	χT expected for non-interacting ions per complex (cm ³ K mol ⁻¹)	χT measured at 300 K per complex (cm ³ K mol ⁻¹)	χT measured at 1.8 K per complex (cm ³ K mol ⁻¹)
Fe ₄ Y ₂ , 1		17.5	14.5	0.02
Fe ₄ Dy ₂ , 2	⁶ H _{15/2}	45.8	42.3	32.6
Fe ₆ Y ₃ , 3		26.3	12.0	0.75
Fe ₆ Dy ₃ , 4	⁶ H _{15/2}	68.8	54.7	31.1

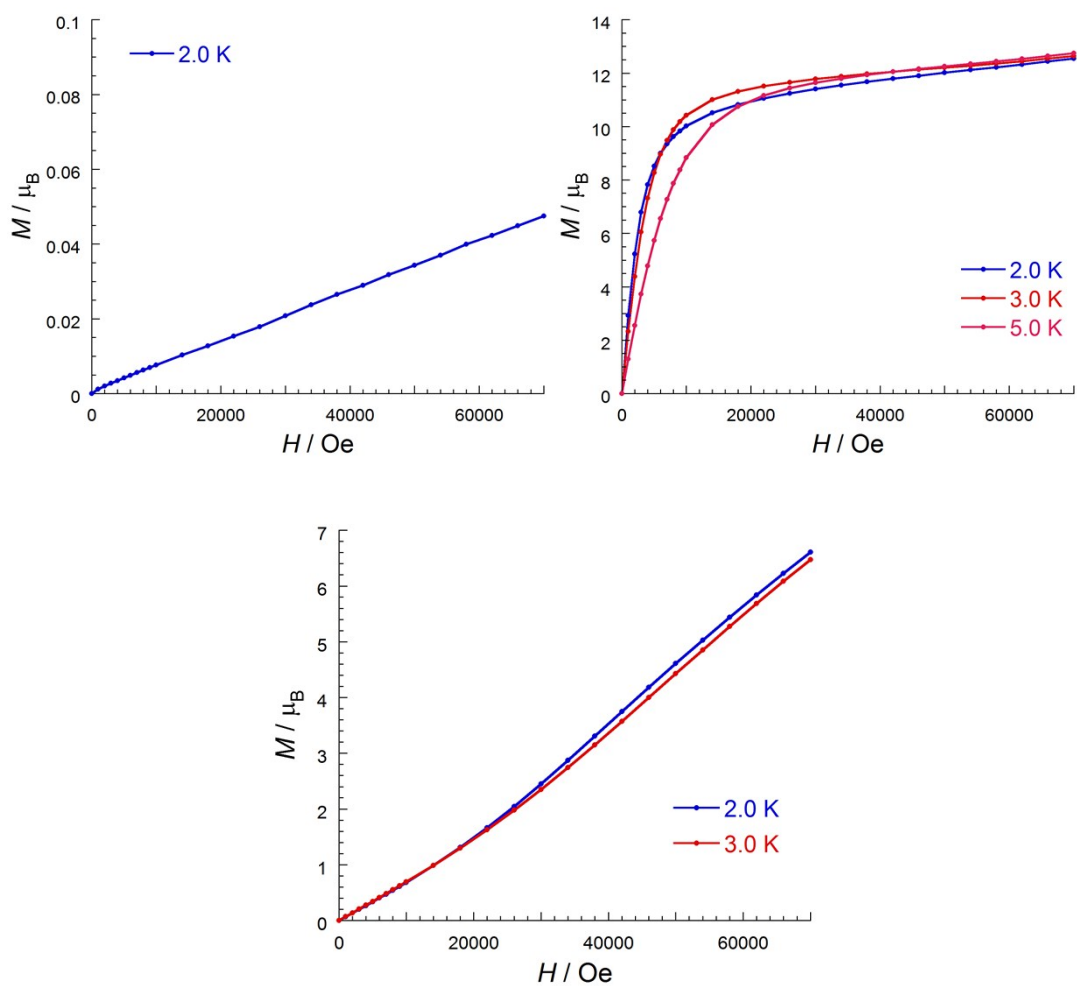


Figure S1 Field dependence of magnetisation at low temperature for compound **1** (top-left), **2** (top-right) and **3** (bottom).

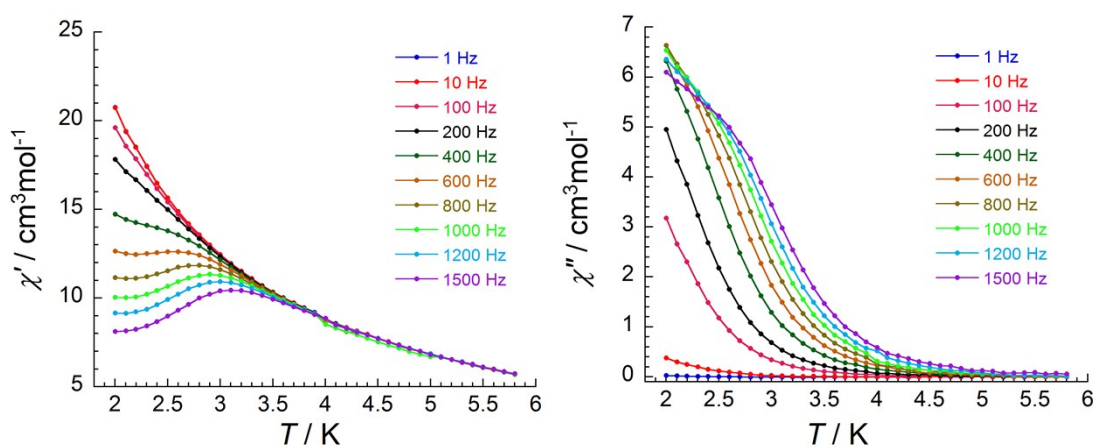


Figure S2 Temperature dependence of the in-phase (χ') (left) and out-of-phase (χ'') (right) ac susceptibility components at the indicated frequencies in zero dc field for **2**.

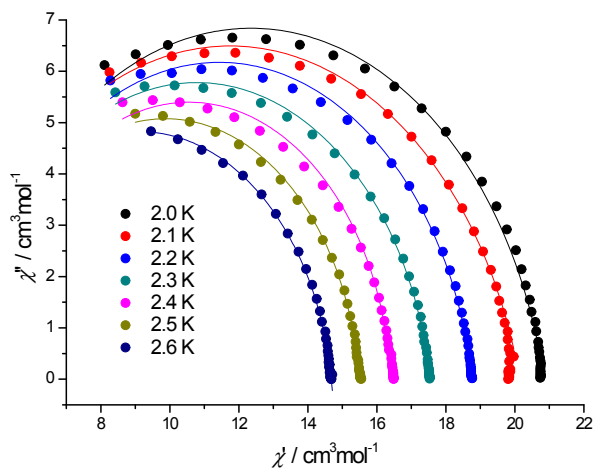


Figure S3 Cole-Cole plots under zero dc field for compound **2**.

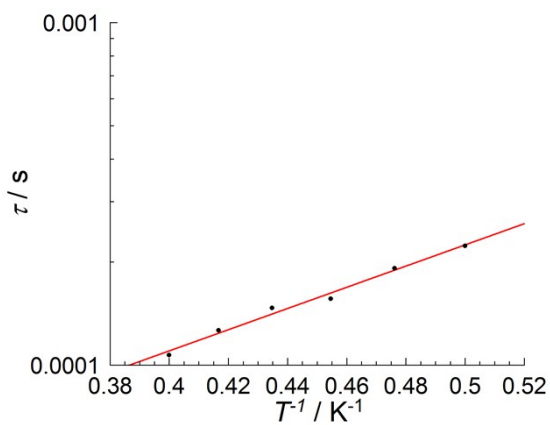


Figure S4 Arrhenius plot using ac data under zero dc field for compound **2**.

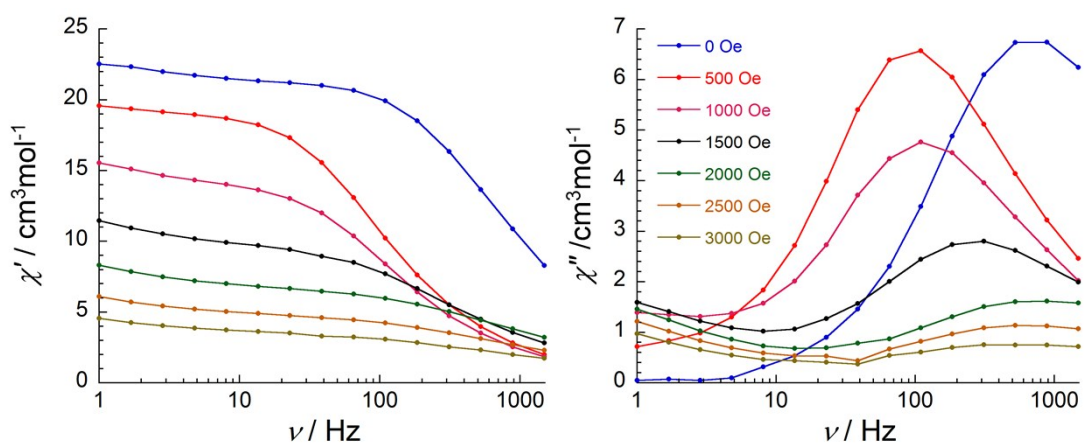


Figure S5 Frequency dependence of the in-phase (χ') (left) and out-of-phase (χ'') (right) ac susceptibility components under the indicated dc fields at 1.8 K for **2**.

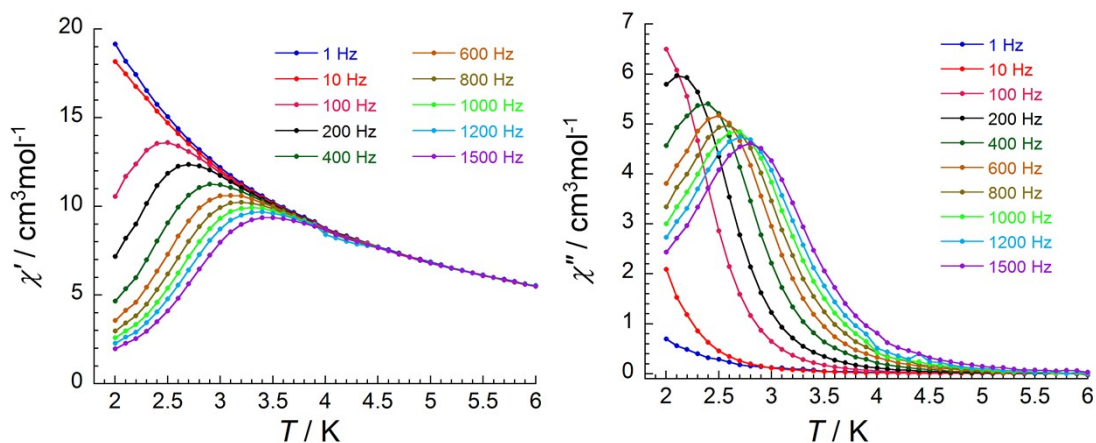


Figure S6 Temperature dependence of the in-phase (χ') (left) and out-of-phase (χ'') (right) ac susceptibility components at the indicated frequencies under 500 Oe dc field for **2**.

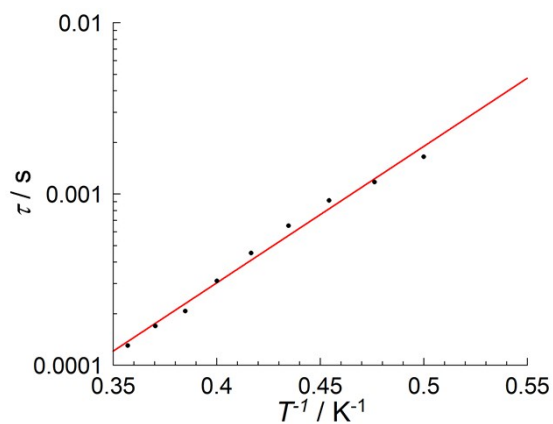


Figure S7 Arrhenius plot using ac data under 500 Oe dc field for compound **2**.

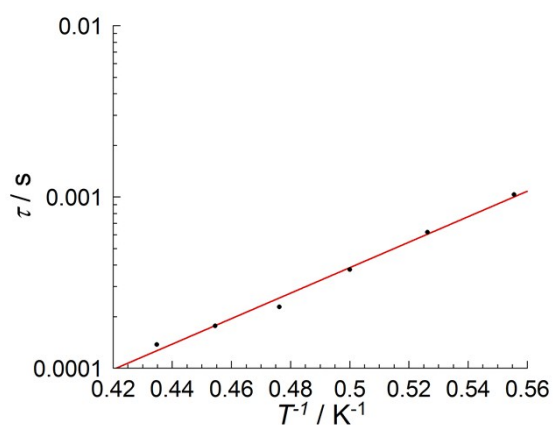


Figure S8 Arrhenius plot using ac data under 1000 Oe dc field for compound **4**.